

CD4049UB, CD4050B Types

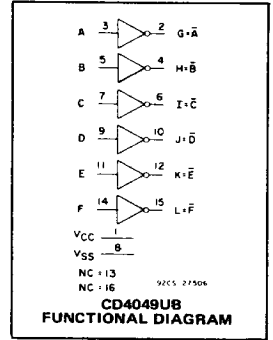
CMOS Hex Buffer/Converters

Features:

- High sink current for driving 2 TTL loads
- High-to-low level logic conversion
- 100% tested for quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- 5-, 10-, and 15-volt parametric ratings

Applications:

- CMOS to DTL/TTL hex converter
- CMOS current "sink" or "source" driver
- CMOS high-to-low logic-level converter



High-Voltage Types (20-Volt Rating)

CD4049UB—Inverting Type

CD4050B—Non-Inverting Type

The RCA-CD4049UB and CD4050B are inverting and non-inverting hex buffers, respectively, and feature logic-level conversion using only one supply (voltage V_{CC}). The input-signal high level (V_{IH}) can exceed the V_{CC} supply voltage when these devices are used for logic-level conversions. These devices are intended for use as CMOS to DTL/TTL converters and can drive directly two DTL/TTL loads. ($V_{CC}=5$ V, $V_{OL}\leq 0.4$ V, and $I_{OL}\geq 3.3$ mA.)

The CD4049UB and CD4050B are designated as replacements for CD4009UB and CD4010B, respectively. Because the CD4049UB and CD4050B require only one power supply, they are preferred over the CD4009UB and CD4010B and should be used in place of the CD4009UB and CD4010B in all inverter, current driver, or logic-level conversion applications. In these applications the CD4049UB and CD4050B are pin compatible with the CD4009UB and CD4010B respectively, and can be substituted for these devices in existing as well as in new designs. Terminal No. 16 is not connected internally on the CD4049UB or CD4050B, therefore, connection to this terminal is of no consequence to circuit operation. For applications not requiring high sink-current or voltage conversion, the CD4069UB Hex Inverter is recommended.

The CD4049UB and CD4050B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead ceramic flat packages (K suffix), and in chip form (H suffix).

MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{CC}) (Voltages referenced to V_{SS} Terminal)	-0.5 to +20 V
INPUT VOLTAGE RANGE, ALL INPUTS	-0.5 to +20.5 V
DC INPUT CURRENT, ANY ONE INPUT	± 10 mA
POWER DISSIPATION PER PACKAGE (P_D):	
For $T_A = -40$ to $+60^\circ\text{C}$ (PACKAGE TYPE E)	500 mW
For $T_A = +60$ to $+85^\circ\text{C}$ (PACKAGE TYPE E)	Derate Linearly at 12 mW/ $^\circ\text{C}$ to 200 mW
For $T_A = -65$ to $+100^\circ\text{C}$ (PACKAGE TYPES D, F, K)	500 mW
For $T_A = +100$ to $+125^\circ\text{C}$ (PACKAGE TYPES D, F, K)	Derate Linearly at 12 mW/ $^\circ\text{C}$ to 200 mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE}$ (All Package Types)	100 mW
OPERATING-TEMPERATURE RANGE (T_A):	
PACKAGE TYPES D, F, K, H	-55 to $+125^\circ\text{C}$
PACKAGE TYPE E	-40 to $+85^\circ\text{C}$
STORAGE TEMPERATURE RANGE (T_{stg})	-65 to $+150^\circ\text{C}$
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79 mm) from case for 10 s max.	$+265^\circ\text{C}$

RECOMMENDED OPERATING CONDITIONS at $T_A=25^\circ\text{C}$, Except as Noted.

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	Min.	Max.	
Supply-Voltage Range (V_{CC}) (For $T_A = \text{Full Package-Temperature Range}$)	3	18	V
Input Voltage Range (V_{IN})	V_{CC}^*	18	V

*The CD4049 and CD4050 have high-to-low-level voltage conversion capability but not low-to-high-level; therefore it is recommended that $V_{IN} \geq V_{CC}$.

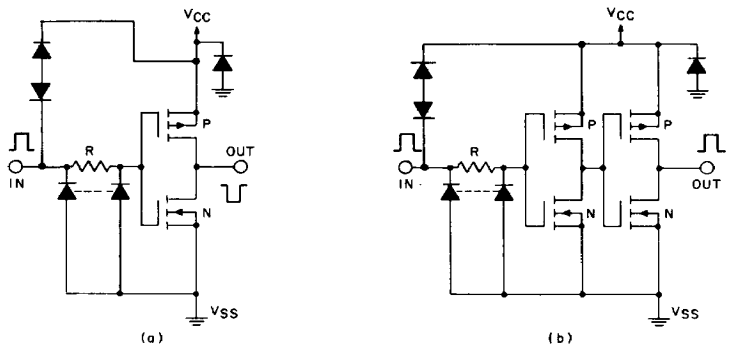
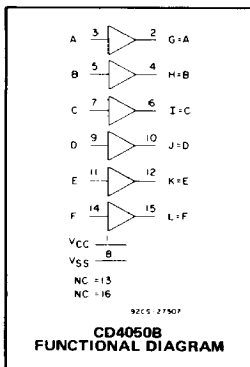


Fig. 1—a) Schematic diagram of CD4049UB, 1 of 6 identical units; b) Schematic diagram of CD4050B, 1 of 6 identical units.

CD4049UB, CD4050B Types

STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			Limits At Indicated Temperatures (°C)							UNITS
	V _O (V)	V _{IN} (V)	V _{CC} (V)	Values at -55, +25, +125 Apply to D, F, K, H Pkgs.				Values at -40, +25, +85 Apply to E Package			
				-55	-40	+85	+125	+25			
								Min.	Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0.5	5	1	1	30	30	—	0.02	1	μA
Output Low (Sink) Current I _{OL} Min.	0.4	0.5	4.5	3.3	3.1	2.1	1.8	2.6	5.2	—	mA
	0.4	0.5	5	4	3.8	2.9	2.4	3.2	6.4	—	
	0.5	0.10	10	10	9.6	6.6	5.6	8	16	—	
Output High (Source) Current I _{OH} Min.	1.5	0.15	15	26	25	20	18	24	48	—	mA
	4.6	0.5	5	-0.81	-0.73	-0.58	-0.48	-0.65	-1.2	—	
	2.5	0.5	5	-2.6	-2.4	-1.9	-1.55	-2.1	-3.9	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0.5	5	0.05				—	0	0.05	V
	—	0.10	10	0.05				—	0	0.05	
	—	0.15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0.5	5	4.95				4.95	5	—	V
	—	0.10	10	9.95				9.95	10	—	
	—	0.15	15	14.95				14.95	15	—	
Input Low Voltage: V _{IL} Max. CD4049UB	4.5	—	5	1				—	—	1	V
	9	—	10	2				—	—	2	
	13.5	—	15	2.5				—	—	2.5	
Input Low Voltage: V _{IL} Max. CD4050B	0.5	—	5	1.5				—	—	1.5	V
	1	—	10	3				—	—	3	
	1.5	—	15	4				—	—	4	
Input High Voltage: V _{IH} Min. CD4049UB	0.5	—	5	4				4	—	—	V
	1	—	10	8				8	—	—	
	1.5	—	15	12.5				12.5	—	—	
Input High Voltage: V _{IH} Min. CD4050B	4.5	—	5	3.5				3.5	—	—	V
	9	—	10	7				7	—	—	
	13.5	—	15	11				11	—	—	
Input Current, I _{IN} Max.	—	0.18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	μA

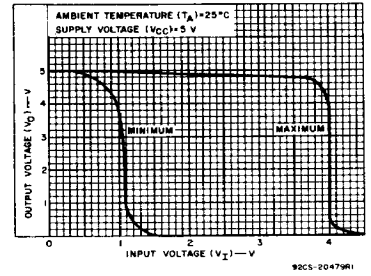


Fig. 2—Minimum and maximum voltage transfer characteristics for CD4049UB.

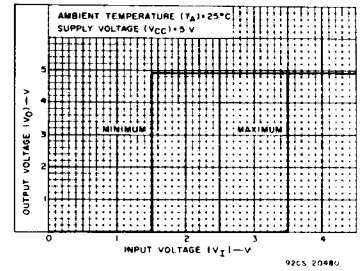


Fig. 3—Minimum and maximum voltage transfer characteristics for CD4050B.

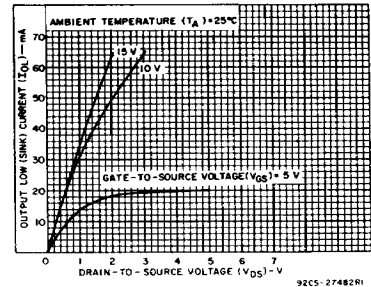


Fig. 4—Typical output low (sink) current characteristics.

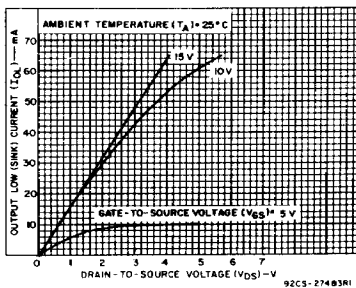


Fig. 5—Minimum output low (sink) current drain characteristics.

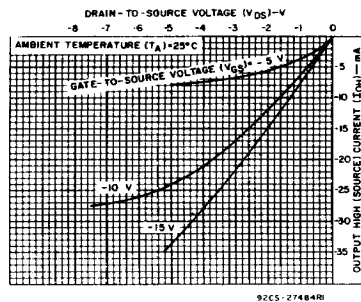


Fig. 6—Typical output high (source) current characteristics.

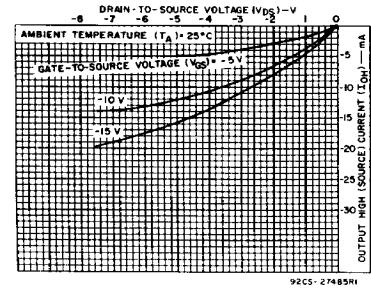


Fig. 7—Minimum output high (source) current characteristics.

CD4049UB, CD4050B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_A = 25^\circ\text{C}$; Input $t_r, t_f = 20\text{ ns}$, $C_L = 50\text{ pF}$, $R_L = 200\text{ k}\Omega$

CHARACTERISTIC	CONDITIONS		LIMITS		UNITS		
	V_{IN}	V_{CC}	Typ.	Max.			
Propagation Delay Time: Low-to-High, t_{PLH}	CD4049UB	5	5	60	120	ns	
		10	10	32	65		
		10	5	45	90		
		15	15	25	50		
		15	5	45	90		
	CD4050B	5	5	70	140		
		10	10	40	80		
		10	5	45	90		
		15	15	30	60		
		15	5	40	80		
High-to-Low, t_{PHL}	CD4049UB	5	5	32	65	ns	
		10	10	20	40		
		10	5	15	30		
		15	15	15	30		
		15	5	10	20		
	CD4050B	5	5	55	110		
		10	10	22	55		
		10	5	50	100		
		15	15	15	30		
		15	5	50	100		
Transition Time: Low-to-High, t_{TLH}		5	5	80	160	ns	
		10	10	40	80		
		15	15	30	60		
		5	5	30	60		
		10	10	20	40		
High-to-Low, t_{THL}		5	5	30	60		
		10	10	20	40		
		15	15	15	30		
		15	15	15	30		
Input Capacitance, C_{IN}	CD4049UB	-	-	15	22.5	pF	
		CD4050B	-	-	5		7.5

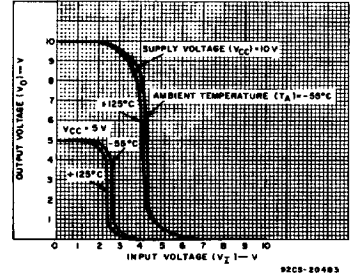


Fig. 8 - Typical voltage transfer characteristics as a function of temperature for CD4049UB.

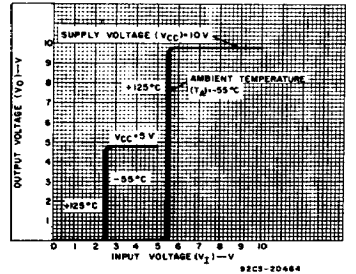


Fig. 9 - Typical voltage transfer characteristics as a function of temperature for CD4050B.

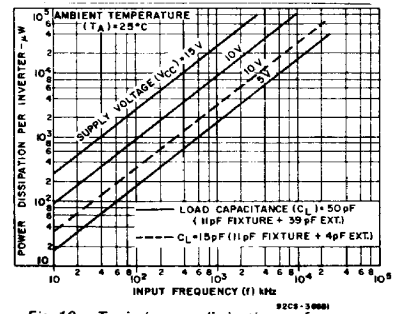


Fig. 10 - Typical power dissipation vs. frequency characteristics.

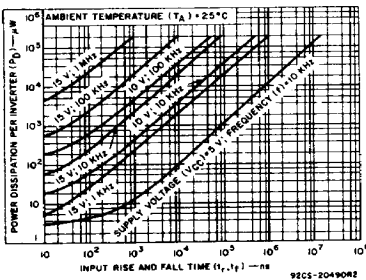


Fig. 11 - Typical power dissipation vs. input rise and fall times per inverter for CD4049UB.

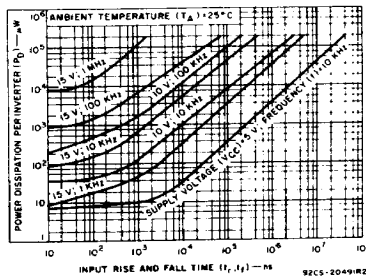


Fig. 12 - Typical power dissipation vs. input rise and fall times per inverter for CD4050B.

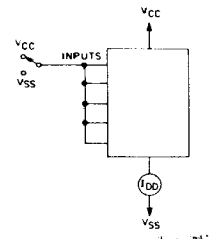


Fig. 13 - Quiescent device current test circuit.

CD4049UB, CD4050B Types

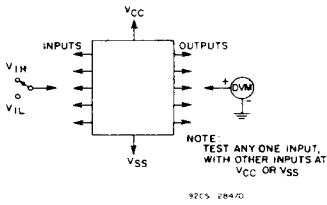


Fig. 14 - Input voltage test circuit.

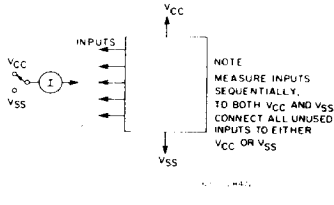


Fig. 15 - Input current test circuit.

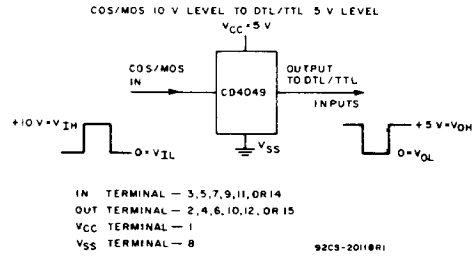
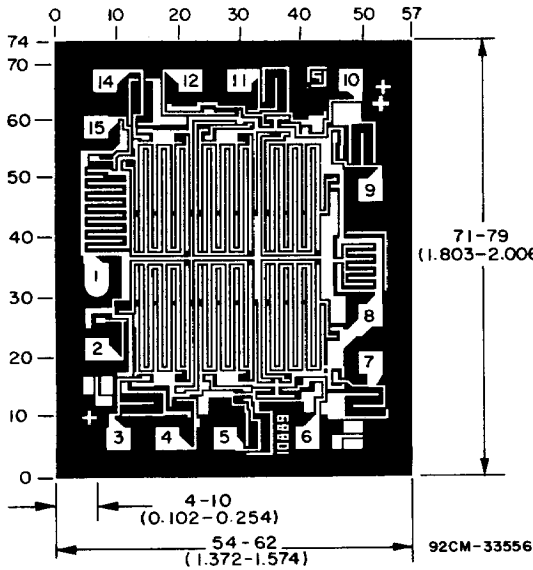


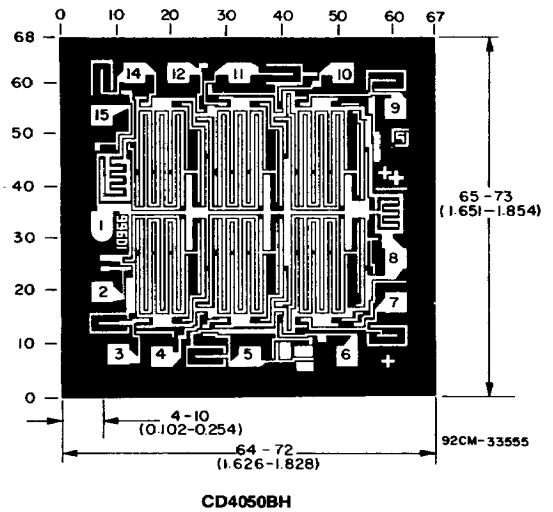
Fig. 16 - Logic-level conversion application.

CHIP PHOTOGRAPHS DIMENSIONS AND PAD LAYOUTS



CD4049UBH

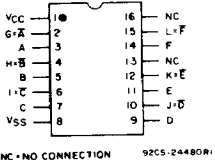
Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).



CD4050BH

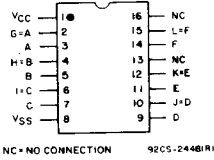
The photographs and dimensions of each CMOS chip represent a chip when it is part of the wafer. When the wafer is separated into individual chips, the angle of cleavage may vary with respect to the chip face for different chips. The actual dimensions of the isolated chip, therefore, may differ slightly from the nominal dimensions shown. The user should consider a tolerance of ± 3 mils to ± 16 mils applicable to the nominal dimensions shown.

TERMINAL ASSIGNMENTS



NC = NO CONNECTION 92CS-24480R1

CD4049UB



NC = NO CONNECTION 92CS-24481R1

CD4050B

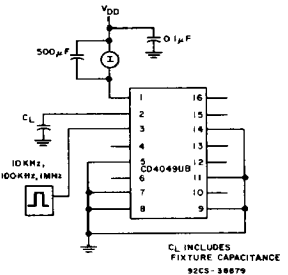


Fig. 17 - Dynamic power dissipation test circuit.